AM26LV31 低压、高速四路差分线路驱动器

1 特性

- 开关频率高达 32MHz
- 由 3.3V 单电源供电运行
- 传播延迟时间：8ns（典型值）
- 脉冲偏移时间：500ps（典型值）
- 高输出驱动电流：±30 mA
- 受控上升和下降时间：3ns（典型值）
- 100Ω 负载时的差分输出电压：1.5V（典型值）
- 超低功耗
  - 直流，0.3mW（最大值）
  - 所有通道 32MHz（空载），385mW（典型值）
- 支持 5V 逻辑输入及 3.3V 电源
- 针对 AM26C31、AM26LS31 和 MB571 的低压引脚对引脚兼容替换产品
- 在断电情况下具有高输出阻抗
- 驱动器输出短路保护电路
- 封装选项包括小巧 (D, NS) 塑料封装

2 应用

- 电机控制：无刷直流和有刷直流
- 现场变送器：温度传感器和压力传感器
- 采用 Modbus 的温度传感器或控制器

3 说明

AM26LV31C 和 AM26LV31I 是具有三态输出的 BiCMOS 四路差分线路驱动器。它们与 TIA/EIA-422-B 和 ITU Recommendation V.11 驱动器类似，但电源电压范围较小。

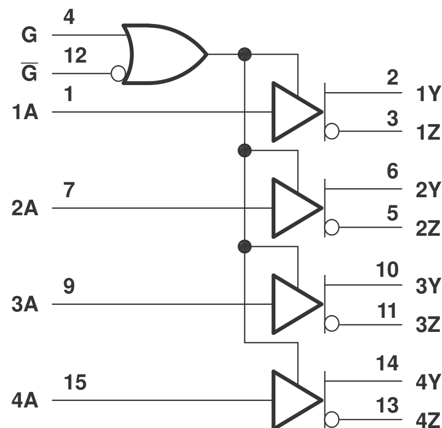
这些器件经过优化，可在高达 32MHz 的开关速率下实现平衡总线传输。输出端可提供非常高的电流，从而驱动双绞线传输线路等平衡线路，并在关断情况下提供高阻抗。四个驱动器均具有使能功能，该功能提供了两种可选输入：有源高电平使能输入和有源低电平使能输入。AM26LV31C 和 AM26LV31I 使用德州仪器 (TI) 专有 LinIMPACT-C60™ 技术进行设计，有助于在不影响速度的情况下实现超低功耗。这些器件会在与 AM26LV32 四路线路接收器配合使用时提供最佳的性能。

AM26LV31C 的额定工作温度范围为 0°C 至 70°C。AM26LV31I 的额定工作温度范围为 -45°C 至 85°C。

封装信息

器件型号	封装[1]	封装尺寸[2]
AM26LV31C	SOIC (D) 16	9.9mm x 6mm
AM26LV31I	SOIC (D) 16	9.9mm x 6mm
	SO (NS) 16	10.2mm x 7.8mm

(1) 有关更多信息，请参阅节 11。
(2) 封装尺寸（长 × 宽）为标称值，并包括引脚（如适用）。



逻辑图（正逻辑）

本资源的原文使用英文撰写。 为方便起见，TI 提供了译文；由于翻译过程中可能使用了自动化工具，TI 不保证译文的准确性。 为确认准确性，请务必访问 ti.com 参考最新的英文版本（控制文档）。

Table of Contents

1 特性........ 1
2 应用........ 1
3 说明........ 1
4 Pin Configuration and Functions........ 3
5 Specifications........ 4
5.1 Absolute Maximum Ratings........ 4
5.2 ESD Ratings........ 4
5.3 Recommended Operating Conditions........ 4
5.4 Thermal Information........ 4
5.5 Electrical Characteristics........ 5
5.6 Switching Characteristics........ 5
5.7 Typical Characteristics........ 6
6 Parameter Measurement Information........ 7
7 Detailed Description........ 10
7.1 Overview........ 10
7.2 Functional Block Diagram........ 10
7.3 Feature Description........ 10
7.4 Device Functional Modes........ 11
8 Application and Implementation........ 12
8.1 Application Information........ 12
8.2 Typical Application........ 12
8.3 Power Supply Recommendations........ 13
8.4 Layout........ 13
9 Device and Documentation Support........ 15
9.1 Device Support........ 15
9.2 接收文档更新通知........ 15
9.3 支持资源........ 15
9.4 Trademarks........ 15
9.5 静电放电警告........ 15
9.6 术语表........ 15
10 Revision History........ 15
11 Mechanical, Packaging, and Orderable Information........ 16

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4 Pin Configuration and Functions

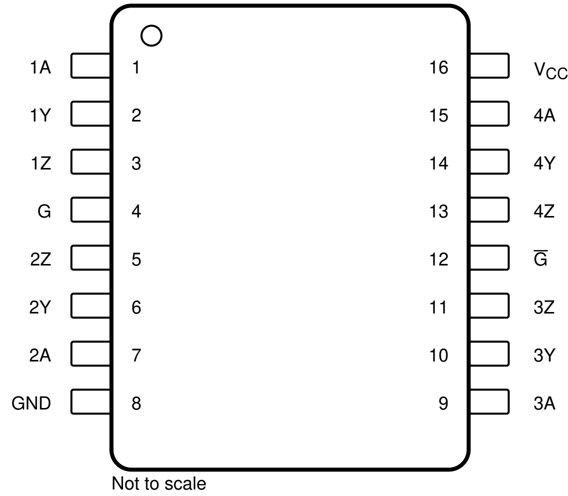

图 4-1. D or NS Package, SOIC 16 Pins (Top View)

表 4-1. Pin Functions

PIN		I/O	DESCRIPTION
NO.	NAME		
1	1A	I	Driver 1 input
2	1Y	O	Driver 1 output
3	1Z	O	Driver 1 inverted output
4	G	I	Active high enable
5	2Z	O	Driver 2 inverted output
6	2Y	O	Driver 2 output
7	2A	I	Driver 2 input
8	GND	—	Ground pin
9	3A	I	Driver 3 input
10	3Y	O	Driver 3 output
11	3Z	O	Driver 3 inverted output
12	$\overline{G}$	I	Active low enable
13	4Z	O	Driver 4 inverted output
14	4Y	O	Driver 4 output
15	4A	I	Driver 4 input
16	V_{CC}	—	Power pin

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5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[(1)]

	MIN	MAX	UNIT
Supply voltage range, V_{CC} [(2)]	–0.3	6	V
Input voltage range, V_I	–0.3	6	V
Output voltage range, V_O	–0.3	6	V
Storage temperature, T_{stg}	–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltage values are with respect to GND.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001[(1)]	±3000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101[(2)]	±250	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. .
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage		3	3.3	3.6	V
V_{IH}	High-level input voltage		2			V
V_{IL}	Low-level input voltage				0.8	V
I_{OH}	High-level output current				–30	mA
I_{OL}	Low-level output current				30	mA
T_A	Operating free-air temperature	AM26LV31C	0		70	°C
		AM26LV31I	–45		85	°C

5.4 Thermal Information

THERMAL METRIC[(1)]		D (SOIC)	NS (SO)	UNIT
		16 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	84.6	88.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	43.5	46.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	43.2	50.7	°C/W
ψ_{JT}	Junction-to-top characterization parameter	10.4	13.5	°C/W
ψ_{JB}	Junction-to-board characterization parameter	42.8	50.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

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5.5 Electrical Characteristics

over recommended operating supply-voltage and free-air temperature ranges (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP[(1)]	MAX	UNIT
V_{IK}	Input clamp voltage	I_I = 18mA				–1.5	V
V_{OH}	High-level output voltage	V_{IH} = 2V,	I_{OH} = –12mA	1.85	2.3		V
V_{OL}	Low-level output voltage	V_{IL} = 0.8V,	I_{OH} = 12mA		0.8	1.05	V
$\|V_{OD}\|$	Differential output voltage[(2)]	R_L = 100Ω		0.95	1.5		V
V_{OC}	Common-mode output voltage			1.3	1.55	1.9	V
$\Delta\|V_{OC}\|$	Change in magnitude of common-mode output voltage[(2)]					±0.2	V
I_O	Output current with power off	V_O = –0.25V or 6V,	V_{CC} = 0			±100	µA
I_{OZ}	Off-state (high-impedance state) output current	V_O = –0.25V or 6V,	G = 0.8V or $\overline{G}$ = 2V			±100	µA
I_H	High-level input current	V_{CC} = 0 or 3V,	V_I = 5.5V			10	µA
I_L	Low-level input current	V_{CC} = 3.6V,	V_I = 0			–10	µA
I_{OS}	Short-circuit output current	V_{CC} = 3.6V,	V_O = 0			–200	mA
I_{CC}	Supply current (all drivers)	V_I = V_{CC} or GND,	No load			100	µA
C_{pd}	Power-dissipation capacitance (all drivers)[(3)]	No load			160		pF

(1) All typical values are at V_{CC} = 3.3V, T_A = 25°C.
(2) $\Delta|V_{OD}|$ and $\Delta|V_{OC}|$ are the changes in magnitude of V_{OD} and V_{OC}, respectively, that occur when the input is changed from a high level to a low level.
(3) C_{pd} determines the no-load dynamic current consumption. $I_S = C_{pd} \times V_{CC} \times f + I_{CC}$

5.6 Switching Characteristics

PARAMETER		TEST CONDITIONS		MIN	TYP[(1)]	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	See 图 6-2		4	8	20	ns
t_{PHL}	Propagation delay time, high- to low-level output			4	8	20	ns
t_t	Transition time (t_r or t_f)				3		ns
SR	Slew rate, single-ended output voltage	See Note [(2)] and 图 6-2			0.3	1	V/ns
t_{PZH}	Output-enable time to high level	See 图 6-3			10	20	ns
t_{PZL}	Output-enable time to low level	See 图 6-4			10	20	ns
t_{PHZ}	Output-disable time from high level	See 图 6-3			10	20	ns
t_{PLZ}	Output-disable time from low level	See 图 6-4			10	20	ns
$t_{sk(p)}$	Pulse skew	f = 32MHz,	See Note [(3)]		0.5	3	ns
$t_{sk(o)}$	Skew limit	f = 32MHz				3	ns
$t_{sk(lim)}$	Skew limit (device to device)	f = 32 MHz,	See Note [(4)]			3	ns

(1) All typical values are at V_{CC} = 3.3V, T_A = 25°C
(2) Slew rate is defined by 方程式 1
(3) Pulse skew is defined as the $|t_{PLH} - t_{PHL}|$ of each channel of the same device.
(4) Skew limit (device to device) is the maximum difference in propagation delay times between any two channels of any two devices.

$$SR = \frac{90\%\,(V_{OH} - V_{OL}) - 10\%\,(V_{OH} - V_{OL})}{t_f}$$, the differential slew rate of V_{CC} is 2 x SR. (1)

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5.7 Typical Characteristics

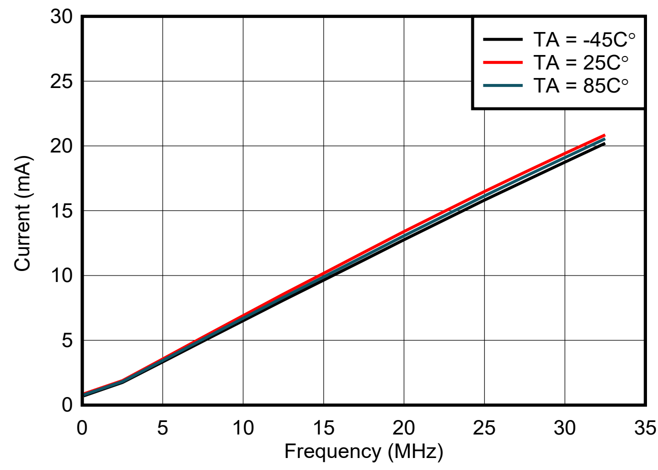


图 5-1. Current vs Frequency

6 Parameter Measurement Information

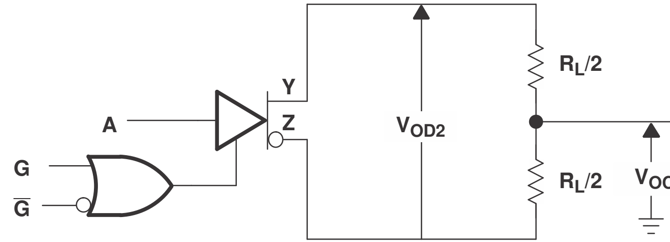
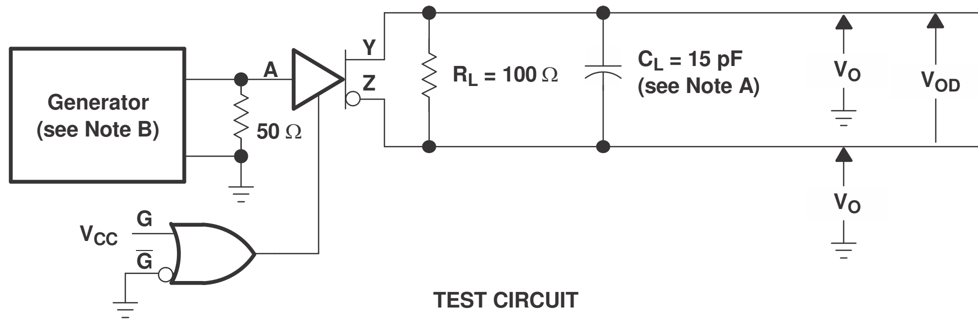
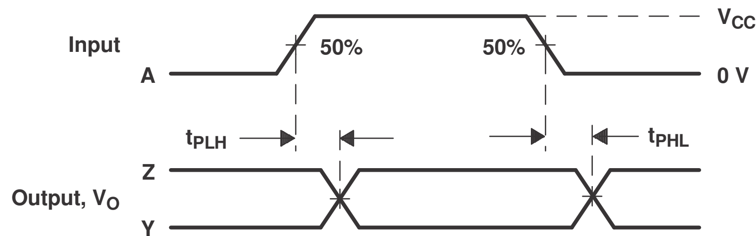
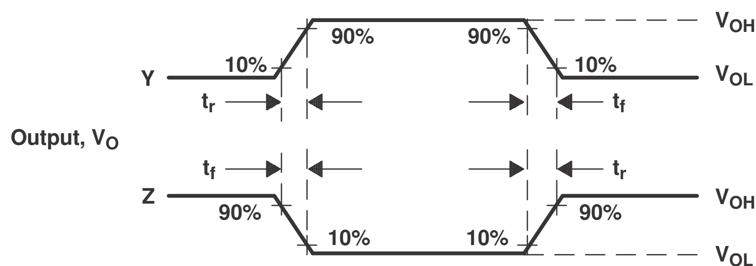


图 6-1. Differential and Common-Mode Output Voltages







A. C_L includes probe and jig capacitance.

B. The input pulse is supplied by a generator having the following characteristics: PRR = 10MHz, Z_O = 50 Ω , 50%v duty cycle, t_r and t_f ⩽ 10ns.

图 6-2. Test Circuit and Voltage Waveforms, t_{PHL} and t_{PLH}

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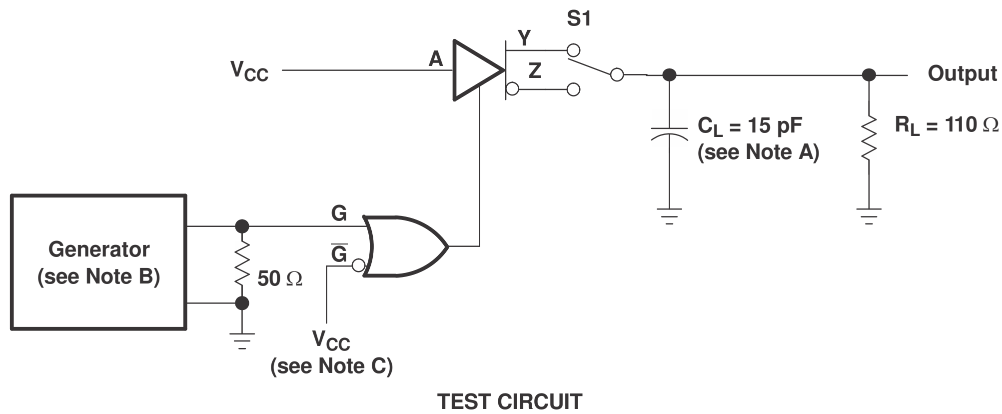
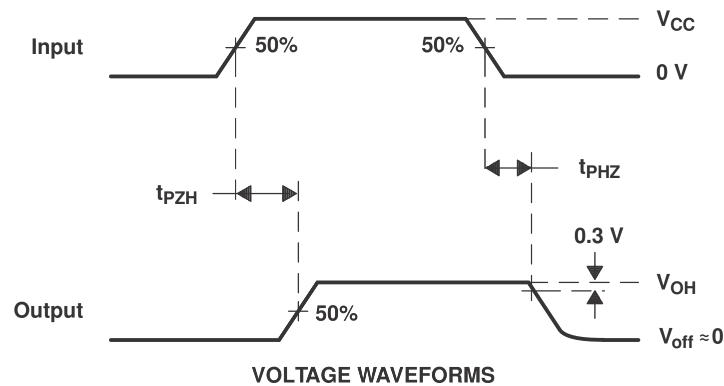


TEST CIRCUIT



VOLTAGE WAVEFORMS

A. C_L includes probe and jig capacitance.
B. The input pulse is supplied by a generator having the following characteristics: PRR = 1MHz, Z_O = 50 Ω , 50%v duty cycle, t_r and t_f (10% to 90%) ⩽ 2ns.
C. To test the active-low enable $\overline{G}$, ground G and apply an inverted waveform to $\overline{G}$.

图 6-3. Test Circuit and Voltage Waveforms, t_{PZH} and t_{PHZ}

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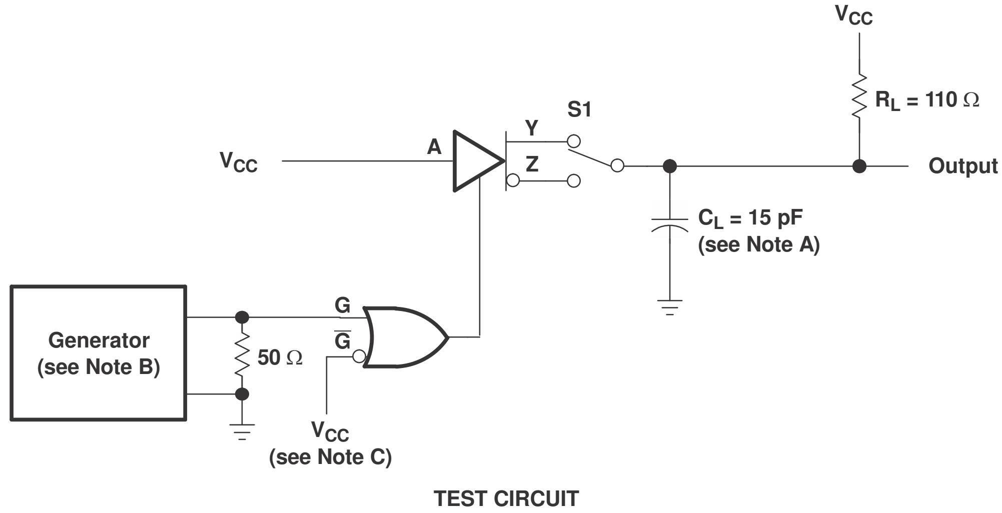
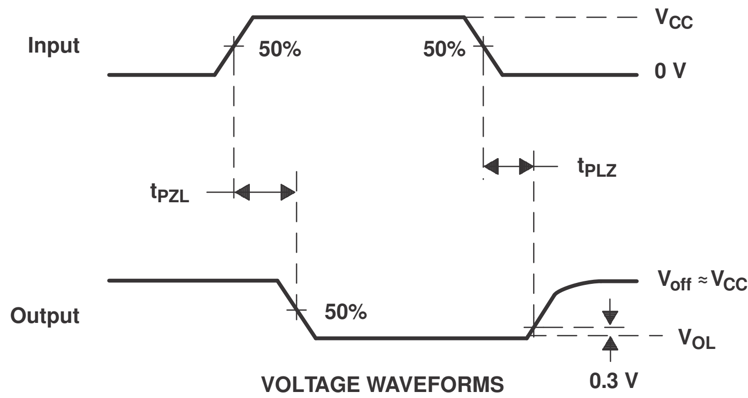


TEST CIRCUIT



VOLTAGE WAVEFORMS

A. C_L includes probe and jig capacitance.

B. The input pulse is supplied by a generator having the following characteristics: PRR = 1MHz, Z_O = 50 Ω , 50%v duty cycle, t_r and t_f (10% to 90%) ⩽ 2ns.

C. To test the active-low enable $\overline{G}$, ground G and apply an inverted waveform to $\overline{G}$.

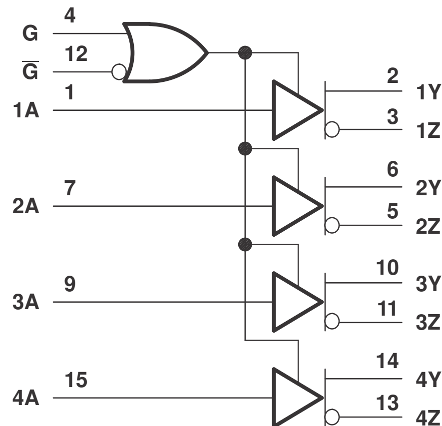
图 6-4. Test Circuit and Voltage Waveforms, t_{PZL} and t_{PLZ}

7 Detailed Description

7.1 Overview

The AM26LV31C and AM26LV31I are BiCMOS quadruple differential line drivers with 3-state outputs. The devices are designed to be similar to TIA/EIA-422-B and ITU Recommendation V.11 drivers with a single 3.3-V power supply. The drivers also integrate active-high and active-low enables for precise device control.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Active high and active low

The devices can be configured using the G and G logic inputs to select transmitter output. A logic high on the G pin or a logic low on the G pin enables the device to operate. These pins are simply a way to configure the logic to match that of the receiving or transmitting controller or microprocessor.

7.3.2 Operates from a 3.3-V Supply with up to 5-V Logic

While the transmitters operate from a single 3.3-V rail, the logic can operate off the same rail or another 5-V rail, making designs much more flexible to communicate to controllers.

7.3.3 High Speed Transmission

The AM26LV31C and AM26LV31I are optimized for balanced-bus transmission at switching rates up to 32 MHz. The devices are designed using Texas Instruments proprietary LinIMPACT-C60™ technology, facilitating ultra-low power consumption without sacrificing speed.

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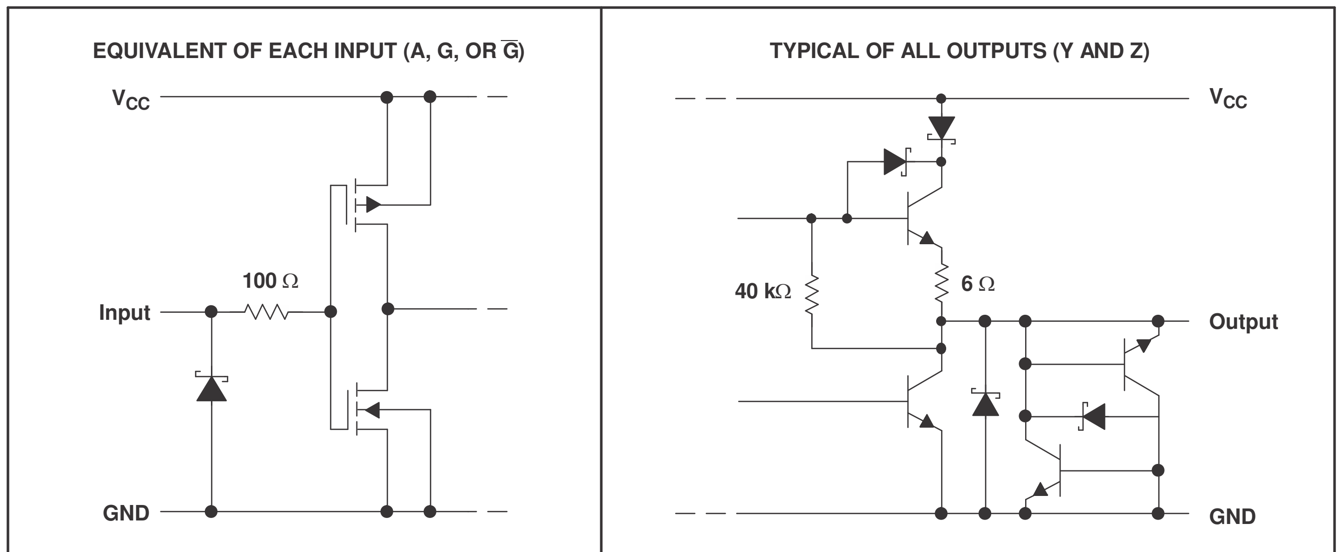
7.4 Device Functional Modes

表 7-1. Function Table[(1)]

INPUT A	ENABLES		OUTPUTS	
	G	$\overline{G}$	Y	Z
H	H	X	H	L
L	H	X	L	H
H	X	L	H	L
L	X	L	L	H
X	L	H	Z	Z

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off)



ll resistor values are nominal.

图 7-1. Schematic (Each Driver)

8 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客 户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

8.1 Application Information

When designing a system that uses drivers, receivers, and transceivers, proper cable termination is essential for highly reliable applications with reduced reflections in the transmission line. If termination is used, it can be placed at the end of the cable near the last receiver. Factors to consider when determining the type of termination usually are performance requirements of the application and the ever-present factor, cost. The different types of termination techniques discussed are unterminated lines, parallel termination, AC termination, and multipoint termination. For laboratory experiments, 100 feet of 100-Ω, 24-AWG, twisted-pair cable (Bertek) was used. A single driver and receiver, TI AM26LV31C and AM26LV32C, respectively, were tested at room temperature with a 3.3-V supply voltage. The first plot shows output waveforms from the driver at the start of the cable (A/B); the second plot shows input waveforms to the receiver at the far end of the cable (Y).

8.2 Typical Application

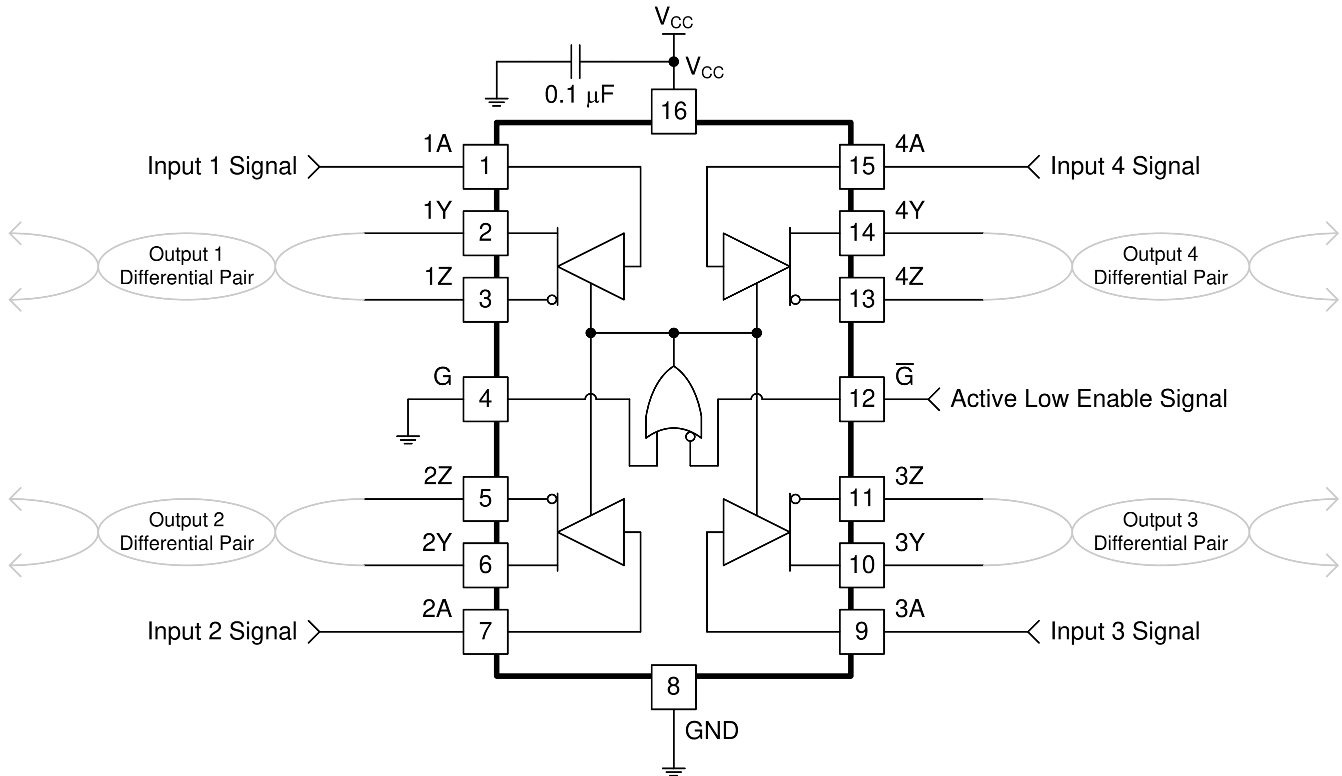


图 8-1. Differential Terminated Configuration With All Channels and Active Low Enable Used

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8.2.1 Design Requirements

Resistor and capacitor (if used) termination values are shown for each laboratory experiment, but vary from system to system. For example, the termination resistor, RT, must be within 20% of the characteristic impedance, Zo, of the cable and can vary from about 80 Ω to 120 Ω.

This example requires the following:

- 3.3-V power source
- RS-485 bus operating at 32 MHz or less
- Connector that ensures the correct polarity for port pins

8.2.2 Detailed Design Procedure

Ensure values in Absolute Maximum Ratings are not exceeded. Supply voltage, V_{IH}, and V_{IL} must comply with Recommended Operating Conditions.

Place the device close to bus connector to keep traces (stub) short to prevent adding reflections to the bus line. If desired, add external fail-safe biasing to ensure 200 mV on the A-B port, if the drive is in high impedance state (see Failsafe in RS-485 data buses).

8.2.3 Application Curves

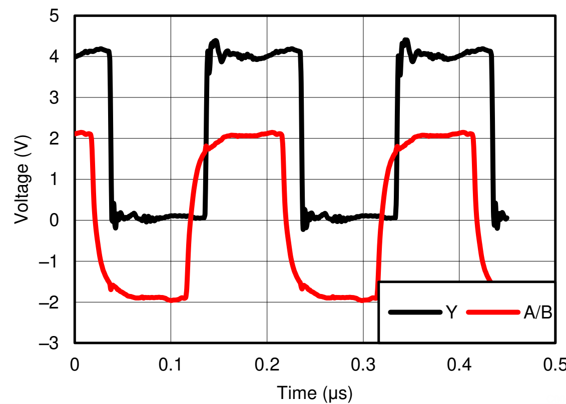

图 8-2. Differential 120-Ω Terminated Output Waveforms (Cat 5E Cable)

8.3 Power Supply Recommendations

Place a 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high impedance power supplies.

8.4 Layout

8.4.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole, as well as the operational amplifier. Bypass capacitors are used to reduce the coupled noise by providing low impedance power sources local to the analog circuitry. Connect low-ESR, 0.1-µF ceramic bypass capacitors between supply pin and ground, placed as close to the device as possible.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current.

- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If it is not possible to keep them separate, it is much better to cross the sensitive trace perpendicular as opposed to in parallel with the noisy trace.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

8.4.2 Layout Example

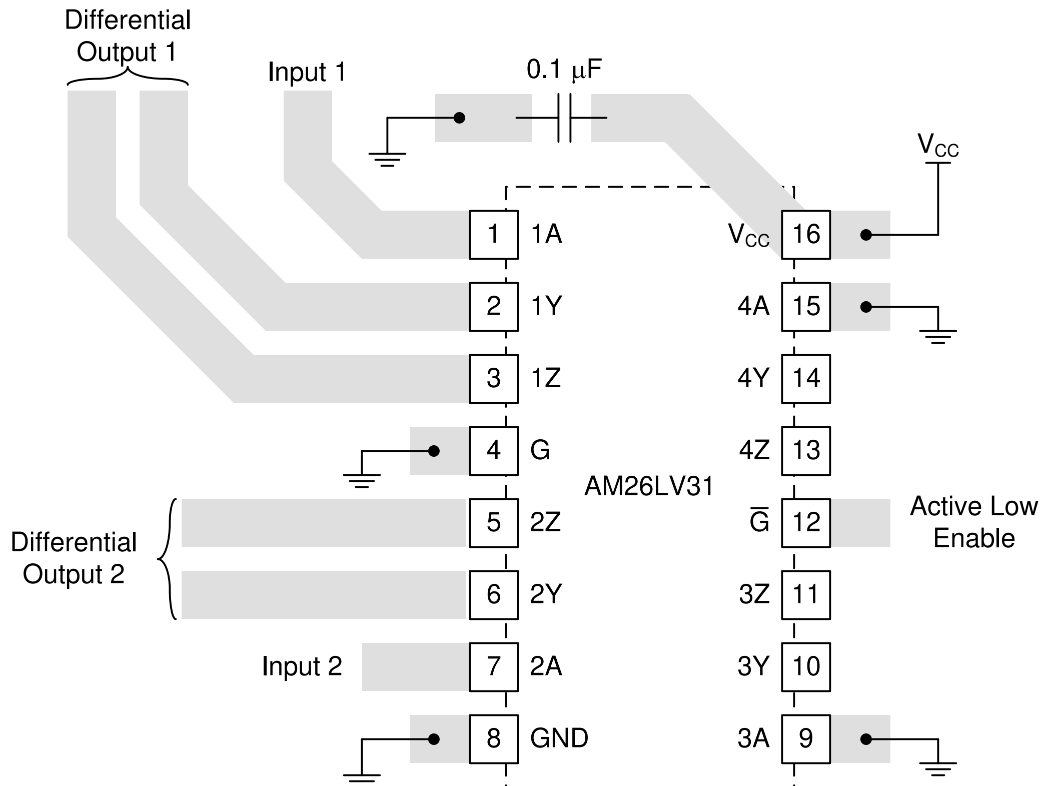

图 8-3. Trace Layout on PCB and Recommendations

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9 Device and Documentation Support

9.1 Device Support

9.1.1 Development Support

9.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击*订阅更新* 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

9.3 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

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9.4 Trademarks

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9.5 静电放电警告

静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

9.6 术语表

TI 术语表 本术语表列出并解释了术语、首字母缩略词和定义。

10 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision H (April 2018) to Revision I (April 2024) **Page**

- 将“器件信息”更改为*封装信息* 表 1
- Changed the *Thermal Information* table values 4
- Changed 图 5-1 6
- Changed the Note B in 图 6-2 7

Changes from Revision G (May 2005) to Revision H (April 2018) **Page**

- 添加了*器件信息* 表、*ESD 等级* 表、*特性说明* 部分、*器件功能模式*、*应用和实施* 部分、*电源相关建议* 部分、*布局* 部分、*器件和文档支持* 部分以及*机械、封装和可订购信息* 部分 1
- Changed the t_{PLH} and t_{PHL} MAX value From: 12 ns To: 20 ns in the *Switching Characteristics* 5
- Changed the $t_{sk(p)}$ and $t_{sk(o)}$ MAX value From: 1.5 ns To: 3 ns in the *Switching Characteristics* 5

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11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
AM26LV31CD	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	0 to 70	AM26LV31C	
AM26LV31CDR	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	0 to 70	AM26LV31C	
AM26LV31ID	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-45 to 85	AM26LV31I	
AM26LV31IDR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-45 to 85	AM26LV31I	Samples
AM26LV31INSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-45 to 85	26LV31I	Samples

[1] The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

[2] **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

[3] MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

[4] There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

[5] Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

[6] Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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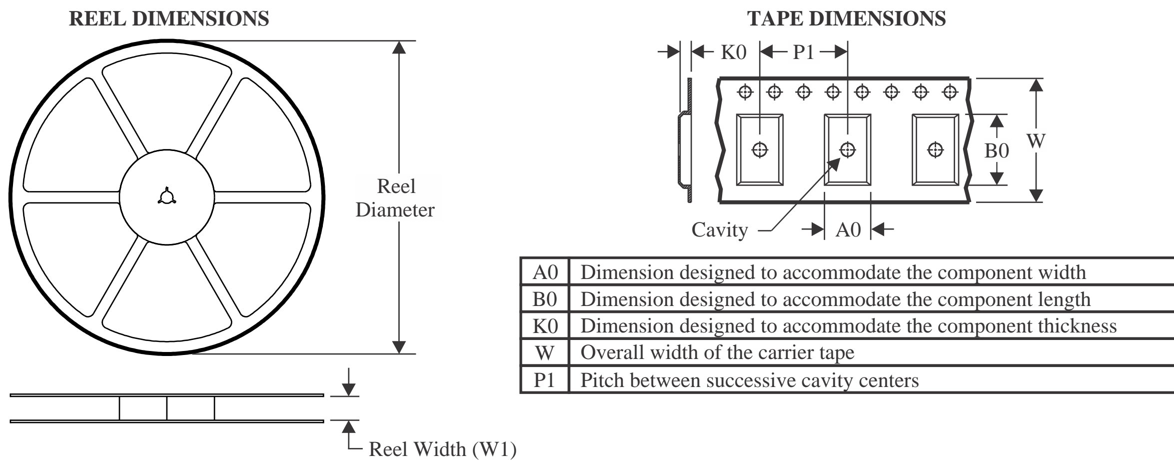
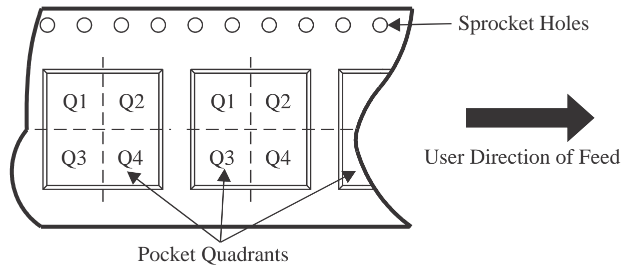
TAPE AND REEL INFORMATION



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

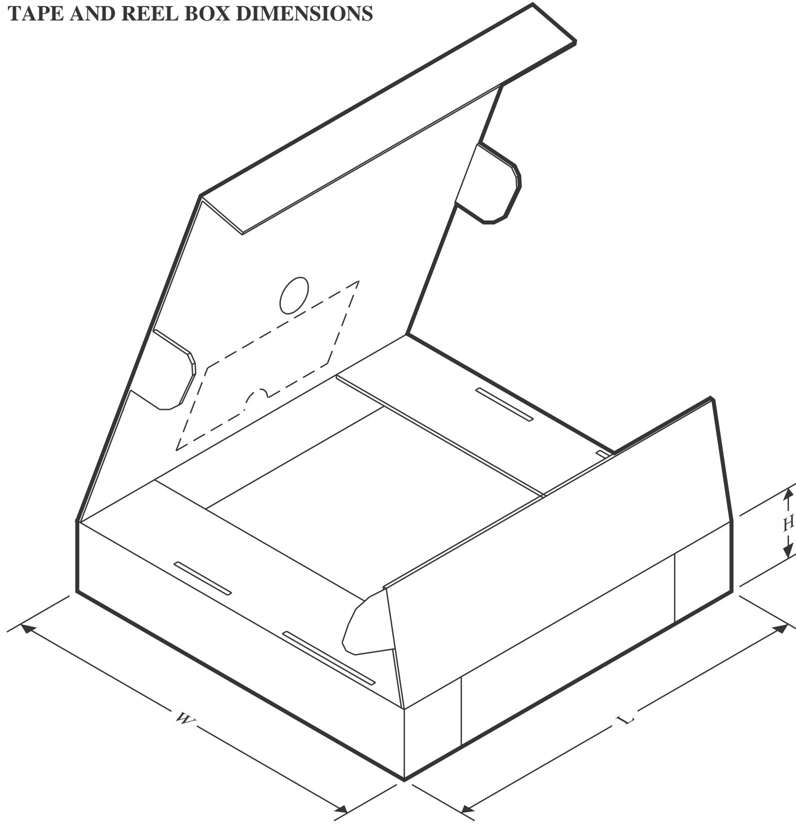
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
AM26LV31CDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26LV31CDRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26LV31CNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
AM26LV31IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26LV31INSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1

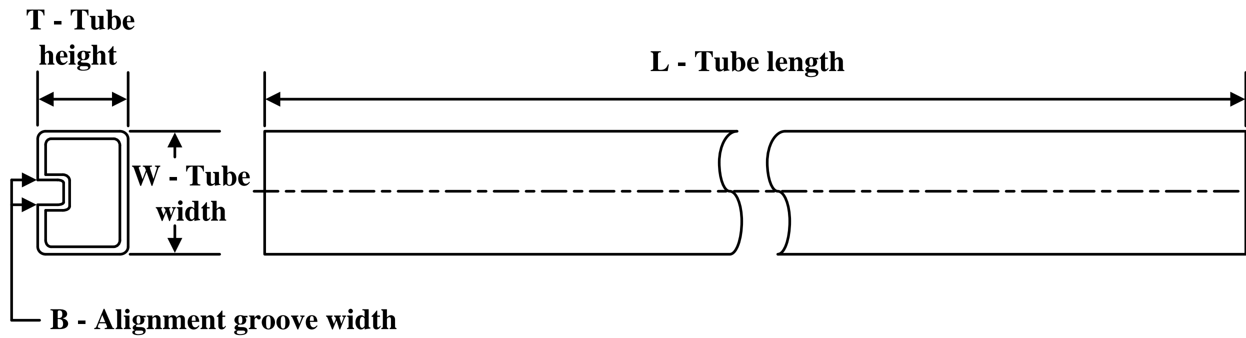
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

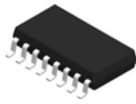
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
AM26LV31CDR	SOIC	D	16	2500	340.5	336.1	32.0
AM26LV31CDRG4	SOIC	D	16	2500	340.5	336.1	32.0
AM26LV31CNSR	SO	NS	16	2000	367.0	367.0	38.0
AM26LV31IDR	SOIC	D	16	2500	340.5	336.1	32.0
AM26LV31INSR	SO	NS	16	2000	356.0	356.0	35.0

TUBE



*All dimensions are nominal

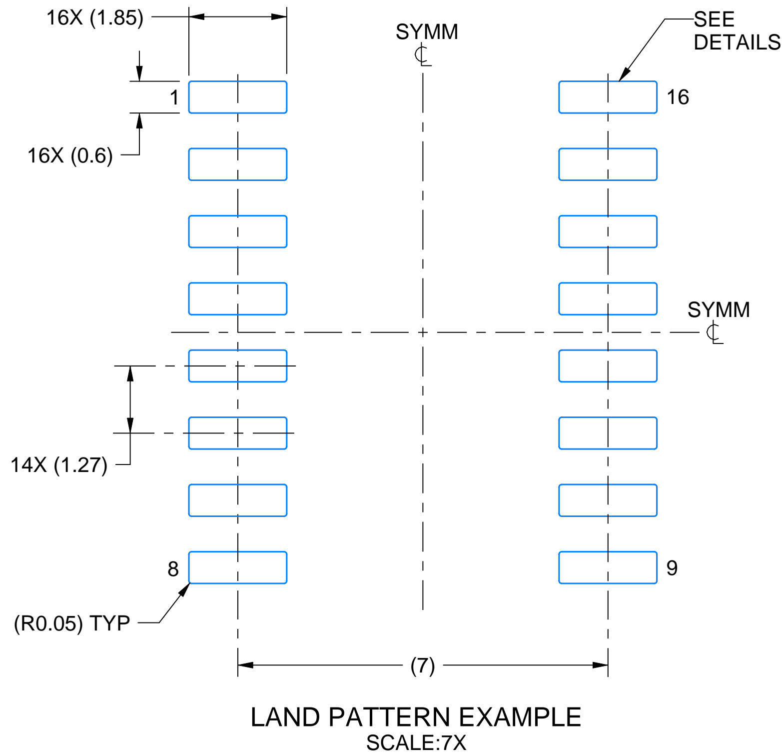
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
AM26LV31CD	D	SOIC	16	40	507	8	3940	4.32
AM26LV31CDE4	D	SOIC	16	40	507	8	3940	4.32
AM26LV31CDG4	D	SOIC	16	40	507	8	3940	4.32
AM26LV31ID	D	SOIC	16	40	507	8	3940	4.32



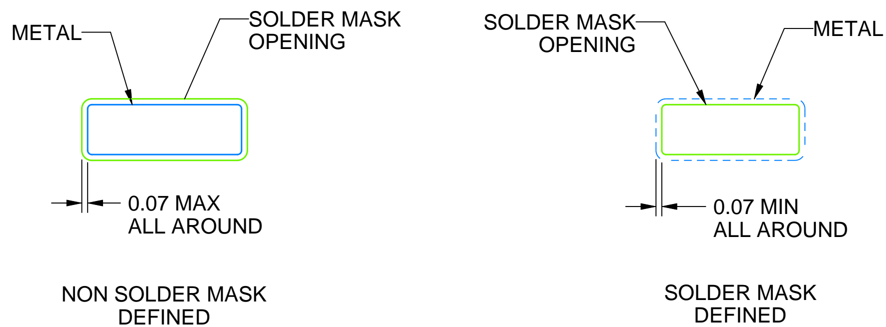
4220735/A 12/2021

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



LAND PATTERN EXAMPLE
SCALE:7X

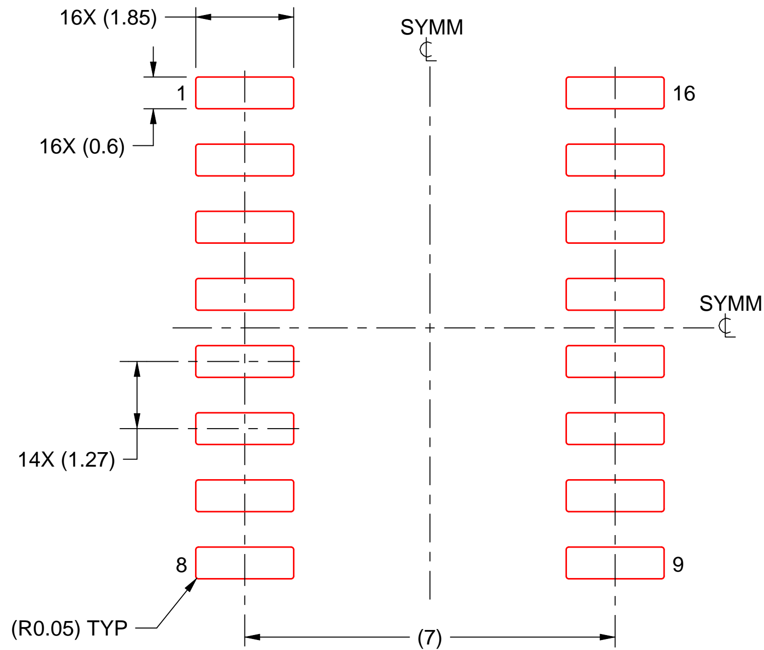


SOLDER MASK DETAILS

4220735/A 12/2021

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

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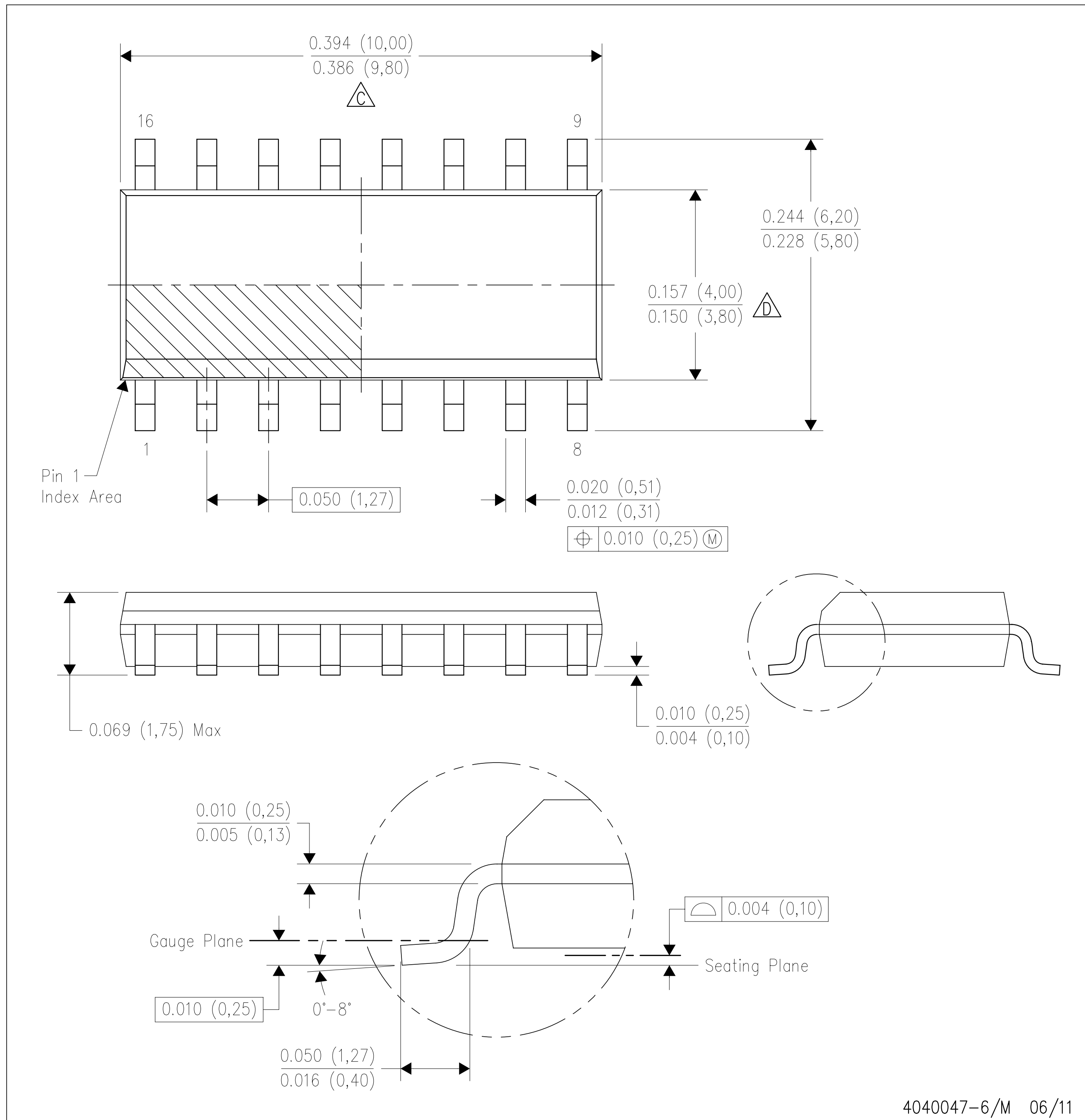
NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

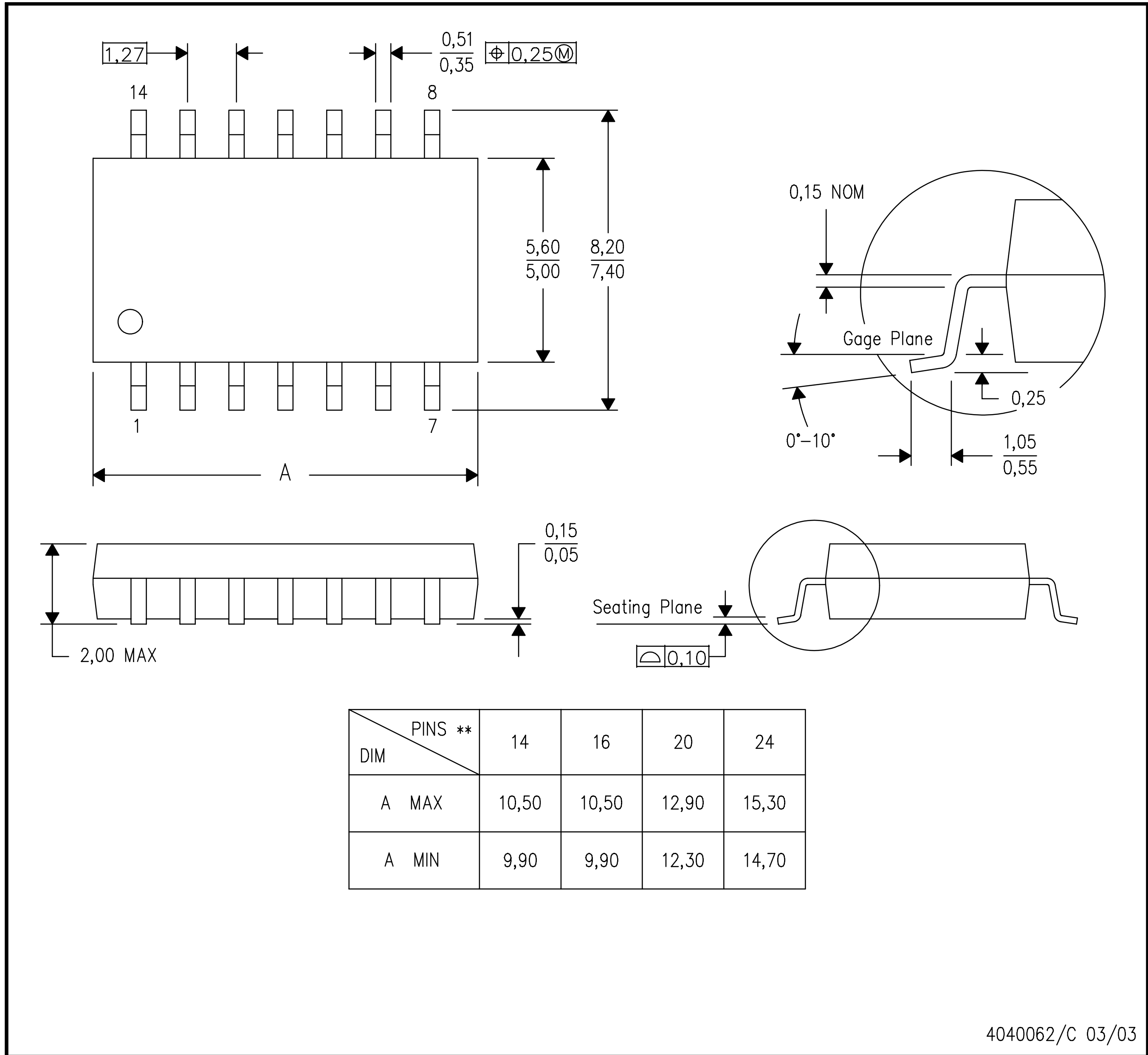
D (R–PDSO–G16) PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

NS (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14-PINS SHOWN



DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

NOTES:
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

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